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Application Number	10594045
Filing Date	2007-06-27
First Named Inventor	Koji Nakayama
Art Unit	2811
Examiner Name	Lynne Ann Gurley
Attorney Docket Number	1217-062849

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CN	4	03038876	WO	A1	2003-05-08	Cree Inc.	<input type="checkbox"/>
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CN	2	LENDENMANN, H. ET AL., "High-Power SiC Diodes: Characteristics, Reliability and Relation to Material Defects", Materials Science Forum, Vols. 389-393 (2002), pp. 1259-1264, Trans Tech Publications, Switzerland	<input type="checkbox"/>
CN	3	LEE, K.S. ET AL., "Surface Preparation of 6H-Silicon Carbide Substrates for Growth of High-Quality SiC Epilayers", Materials Science Forum, Vols. 457-460 (2004), pp. 797-800	<input type="checkbox"/>

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